

# **Precision UV-QE Measurements at Optical Detectors**

## with a special calibrated test bench

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## Summary:

In the detector laboratory of ESO a detector test bench was developed and recently improved in order to get high precision UV-QE measurements of optical CCD detectors. During the last years the calibration of the test bench was refined as well as the reliability of the resulting quantum efficiency results, especially in the critical ultra-violet range of the spectrum. The poster describes the principle, the methods and some tricks to get more precise and reliable UV quantum efficiency values with only small errors. This is currently needed for the new VLT CUBES instrument project, which is a spectrograph mainly in the UV spectral range. In addition this poster gives a comprehensive overview of the used test bench, which is now fully automated and controlled by a Windows PC using LabView, IDL and the very comfortable PRiSM image processing software.

#### **Step 1: Absolute calibrated photo-diode Step 7: UV and gas sensitivation** of CCDs to improve UV-QE New (2013) Hamamatsu Photo Diode S1337-1010BQ

## **Step 6: Repeated QE CCD measurements**





#### Package size 15 x 16.5 mm Photosensitive area size 10 x 10 mm Window material Quarz This diode was selected because of very high hard-UV sensitivity.

Wav. [nm] Diode	300	310	320	330	340	350	360	370	380	390	400
sensitivity [mA/W]											
Hamamatsu	19	93	112	128	139	146	153	160	174	193	205
NPL (Error 1%)	28	72	116	132	138	143	148	158	170	186	201

The diode is calibrated by Hamamatsu and the calibration was compared with a calibration of the same diode by National Physical Laboratory (NPL) United Kingdom.

Diode decay in	Wav. [nm]	Diode 2006	Diode 2012	New Diode 2013
hard UV range	300	19	11	129
after 6 years and	310	93	12	137
newly selected	320	112	21	142
diode (values in	330	128	113	145
[mA/W]):	340	139	135	148
T	350	146	145	148

#### **Step 2: Electrometer for diode** current measurements



Keithley 6514 System Electrometer with accuracy of 0.01 pA

#### Linearity calibration of the electrometer:



QE of UVES blue e2v CCD 44-82 UV AR before, directly after and two months after treatment



At some CCD detectors the UV-QE can be improved up to 50 % by a treatment with temperature, UV light and oxygen gas. To make this improvement stable the detector has to be kept cool and/or in a perfect vacuum.

#### **Step 4: Relative test bench calibration**





After the cross-calibration of the sphere diode with the detector position diode with a stabilized light source we get for each wavelength the ratio

ESO dark box

Diode

error

Precision UV-QE results of MIT/LL-phase 4-CCD and e2v CCD 44-82

64.68 0.04 400 Final precise result of CUBE

candidate MIT/LL-phase 4-CCD

#### High precision QE measurement error budget

1. Calibration error of the absolutely calibrated photodiode at Hamamatsu: 1% between 400 and 1000 nm and estimated 2 - 3 % below 400 nm

2. Error of Keithley electrometer meaurements during calibration at CCD position: max. 1 %

3. Error of Keithley electrometer meaurements during calibration at sphere position: max. 1 %

4. Error of Keithley electrometer meaurements during CCD tests at sphere position: max. 1 %

5. Error of CCD conversion-factor calculation: 1 %

6. Statistical error of CCD signal: 0.7 %

7. Variation of QE over measured CCD area (1024 x 512 pixel in the centre): approx. 2 %

RESULT: All these errors have to be added with the square-root- law, which results in: 3 % (relative error)

CCD	MIT/LL phase 4	e2v 44-82	e2v 44-82
CCD	(CUBES candidate)	(UVES blue)	(X-Shooter blue arm)
QE @ 310 nm	68.1 ± 2.0 %	82.9 ± 2.5 %	70.5 ± 2.1 %

310 nm is the UV-wavelength of interest for the planned CUBES VLT instrument.



MIT/LL Phase 4 CCD

#### **Step 5: CCD gain** calculation and calibration

CCD gain [e<sup>-</sup>/ADU]

HAMAMATSU

photo-diode

at sphere

LABSPHERE

CSTM-US-200-SF

integrating sphere

**ESO Teepee JUMO** temperature controller



nt ratio between	300	2.2362E+07	1.7542E-11	6.8371E+04	2.6435E-14
tector plane diode	310	4.1222E+07	3.4392E-11	5.5955E+04	2.1193E-14
	320	7.4772E+07	6.3520E-11	3.1517E+04	2.4202E-14
	330	1.3530E+08	1.1507E-10	8.0879E+04	3.5189E-14
Diode	340	2.1401E+08	1.8197E-10	1.0187E+05	3.3314E-14
ratio	350	3.6574E+08	3.0551E-10	1.0859E+05	4.1744E-14
	360	5.0010E+08	4.0345E-10	1.8175E+05	1.6076E-13
350 400 velength [nm]	370	6.6013E+08	5.2974E-10	1.5346E+06	3.4030E-14
bench cross calibration	380	9.0075E+08	7.6790E-10	1.3439E+06	1.5937E-12
	390	1.1722E+09	1.0731E-09	2.1636E+05	1.4432E-13

ESO

CCD head

1.14 Linear fit 1.12 -Best CCD gain value 1.10 1.08 1.00 0.98 Single gain measurement values 0.96 0.94 + 0.92 0.90 9000 11000 13000

The CCD gain is calculated at different illumination levels using the statistical method and plotted as given. Then a fit is done from values above 1000 and below 15000 ADU and the intersection with the y-axis gives the best CCD gain value.

## 5937E-12 .4432E-13 **Optical Detector Test Bench**



Power Supply 69931 and ORIEL Light Intensity Controller in order to compensate short term and long term oscillations and flickering of the light source.

**Light Source Stabilization** 

with NEWPORT Radiometric

CCD mean leve

[ADU]

**ORIEL MS257** 

Double

Monochromator

e2v CCD 44-82

Halogen light source: ORIEL 60000 Q housing, **ORIEL 60090 interface plate, ORIEL LSC115 condensor** and OSRAM HLX Xenophot 24 V/150 W halogen lamp

